

# High Voltage Thyristor Module

$V_{RRM}$  = 2x2000 V

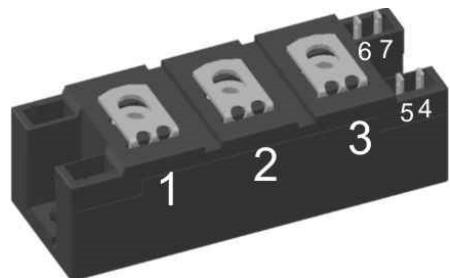
$I_{TAV}$  = 165 A

$V_T$  = 1.08 V

## Phase leg

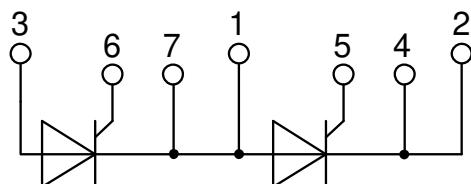
### Part number

**MCC161-20io1**



Backside: isolated

 E72873



### Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al<sub>2</sub>O<sub>3</sub>-ceramic

### Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

### Package: Y4

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

### Disclaimer Notice

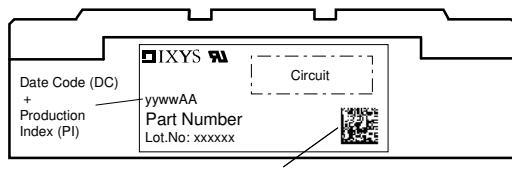
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**Thyristor**

| Symbol         | Definition   | Conditions  | Ratings   |      |              |               |
|----------------|--|---|---|------|--------------|---------------|
|                |  |   | min.  | typ. | max.         |               |
| $V_{RSM/DSM}$  | max. non-repetitive reverse/forward blocking voltage | $T_{VJ} = 25^\circ C$   |   |      | 2100         | V             |
| $V_{RRM/DRM}$  | max. repetitive reverse/forward blocking voltage     | $T_{VJ} = 25^\circ C$   |   |      | 2000         | V             |
| $I_{R/D}$      | reverse current, drain current                       | $V_{R/D} = 2000 \text{ V}$<br>$V_{R/D} = 2000 \text{ V}$  | $T_{VJ} = 25^\circ C$<br>$T_{VJ} = 125^\circ C$ |      | 400<br>40    | $\mu A$<br>mA |
| $V_T$          | forward voltage drop                                 | $I_T = 150 \text{ A}$   | $T_{VJ} = 25^\circ C$                           |      | 1.14         | V             |
|                |  | $I_T = 300 \text{ A}$   |   |      | 1.36         | V             |
|                |  | $I_T = 150 \text{ A}$<br>$I_T = 300 \text{ A}$  | $T_{VJ} = 125^\circ C$                          |      | 1.08<br>1.36 | V             |
| $I_{TAV}$      | average forward current                              | $T_C = 85^\circ C$  | $T_{VJ} = 125^\circ C$                          |      | 165          | A             |
| $I_{T(RMS)}$   | RMS forward current                                  | 180° sine   |   |      | 300          | A             |
| $V_{T0}$       | threshold voltage                                    | $r_T$<br>slope resistance } for power loss calculation only   | $T_{VJ} = 125^\circ C$                          |      | 0.80         | V             |
|                | slope resistance                                     |   |   |      | 1.6          | $m\Omega$     |
| $R_{thJC}$     | thermal resistance junction to case                  |   |   |      | 0.155        | K/W           |
| $R_{thCH}$     | thermal resistance case to heatsink                  |   |   | 0.07 |              | K/W           |
| $P_{tot}$      | total power dissipation                              |   | $T_C = 25^\circ C$                              |      | 645          | W             |
| $I_{TSM}$      | max. forward surge current                           | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$   | $T_{VJ} = 45^\circ C$                           |      | 6.00         | kA            |
|                |  | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$  | $V_R = 0 \text{ V}$                             |      | 6.48         | kA            |
|                |  | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$   | $T_{VJ} = 125^\circ C$                          |      | 5.10         | kA            |
|                |  | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$  | $V_R = 0 \text{ V}$                             |      | 5.51         | kA            |
| $I^2t$         | value for fusing                                     | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$   | $T_{VJ} = 45^\circ C$                           |      | 180.0        | $kA^2s$       |
|                |  | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$  | $V_R = 0 \text{ V}$                             |      | 174.7        | $kA^2s$       |
|                |  | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$   | $T_{VJ} = 125^\circ C$                          |      | 130.1        | $kA^2s$       |
|                |  | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$  | $V_R = 0 \text{ V}$                             |      | 126.3        | $kA^2s$       |
| $C_J$          | junction capacitance                                 | $V_R = 700 \text{ V}$ $f = 1 \text{ MHz}$   | $T_{VJ} = 25^\circ C$                           | 195  |              | pF            |
| $P_{GM}$       | max. gate power dissipation                          | $t_p = 30 \mu s$  | $T_C = 125^\circ C$                             |      | 120          | W             |
|                |  | $t_p = 500 \mu s$   |   |      | 60           | W             |
| $P_{GAV}$      | average gate power dissipation                       |   |   |      | 8            | W             |
|                |  |   |   |      |              |               |
| $(di/dt)_{cr}$ | critical rate of rise of current                     | $T_{VJ} = 125^\circ C; f = 50 \text{ Hz}$ repetitive, $I_T = 500 \text{ A}$   |   |      | 150          | $A/\mu s$     |
|                |  | $t_p = 200 \mu s; di_G/dt = 0.5 \text{ A}/\mu s;$   |   |      |              |               |
|                |  | $I_G = 0.5 \text{ A}; V = \frac{2}{3} V_{DRM}$ non-repet., $I_T = 160 \text{ A}$  |   |      | 500          | $A/\mu s$     |
| $(dv/dt)_{cr}$ | critical rate of rise of voltage                     | $V = \frac{2}{3} V_{DRM}$   | $T_{VJ} = 125^\circ C$                          |      | 1000         | $V/\mu s$     |
|                |  | $R_{GK} = \infty$ ; method 1 (linear voltage rise)  |   |      |              |               |
| $V_{GT}$       | gate trigger voltage                                 | $V_D = 6 \text{ V}$   | $T_{VJ} = 25^\circ C$                           |      | 2            | V             |
|                |  |   | $T_{VJ} = -40^\circ C$                          |      | 2.6          | V             |
| $I_{GT}$       | gate trigger current                                 | $V_D = 6 \text{ V}$   | $T_{VJ} = 25^\circ C$                           |      | 150          | mA            |
|                |  |   | $T_{VJ} = -40^\circ C$                          |      | 200          | mA            |
| $V_{GD}$       | gate non-trigger voltage                             | $V_D = \frac{2}{3} V_{DRM}$   | $T_{VJ} = 125^\circ C$                          |      | 0.25         | V             |
| $I_{GD}$       | gate non-trigger current                             |   |   |      | 10           | mA            |
| $I_L$          | latching current                                     | $t_p = 30 \mu s$<br>$I_G = 0.45 \text{ A}; di_G/dt = 0.45 \text{ A}/\mu s$  | $T_{VJ} = 25^\circ C$                           |      | 200          | mA            |
| $I_H$          | holding current                                      | $V_D = 6 \text{ V}$ $R_{GK} = \infty$   | $T_{VJ} = 25^\circ C$                           |      | 200          | mA            |
| $t_{gd}$       | gate controlled delay time                           | $V_D = \frac{1}{2} V_{DRM}$<br>$I_G = 0.5 \text{ A}; di_G/dt = 0.5 \text{ A}/\mu s$   | $T_{VJ} = 25^\circ C$                           |      | 2            | $\mu s$       |
| $t_q$          | turn-off time  | $V_R = 100 \text{ V}; I_T = 160 \text{ A}; V = \frac{2}{3} V_{DRM}$ $T_{VJ} = 100^\circ C$<br>$di/dt = 10 \text{ A}/\mu s$ $dv/dt = 20 \text{ V}/\mu s$ $t_p = 200 \mu s$ |   | 150  |              | $\mu s$       |

**Package Y4**

| Conditions    |   |  | min.  | typ. | max.         | Unit   |
|---------------|---|--|---|------|--------------|--------|
| $I_{RMS}$     | <i>RMS current</i>  | per terminal                                     |   |      | 300          | A      |
| $T_{VJ}$      | <i>virtual junction temperature</i>                                 |  | -40   |      | 125          | °C     |
| $T_{op}$      | <i>operation temperature</i>  |  | -40   |      | 100          | °C     |
| $T_{stg}$     | <i>storage temperature</i>  |  | -40   |      | 125          | °C     |
| <b>Weight</b> |   |  |   | 150  |              | g      |
| $M_D$         | <i>mounting torque</i>  |  | 2.25  |      | 2.75         | Nm     |
| $M_T$         | <i>terminal torque</i>  |  | 4.5   |      | 5.5          | Nm     |
| $d_{Spp/App}$ | <i>creepage distance on surface / striking distance through air</i> |  | <i>terminal to terminal</i>                 | 14.0 | 10.0         | mm     |
| $d_{Spb/Apb}$ |   |  | <i>terminal to backside</i>                 | 16.0 | 16.0         | mm     |
| $V_{ISOL}$    | <i>isolation voltage</i>  | $t = 1 \text{ second}$<br>$t = 1 \text{ minute}$ | 50/60 Hz, RMS; $I_{ISOL} \leq 1 \text{ mA}$ |      | 3600<br>3000 | V<br>V |

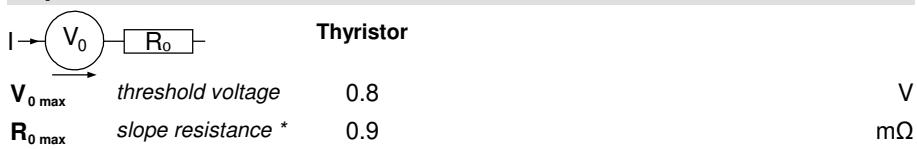


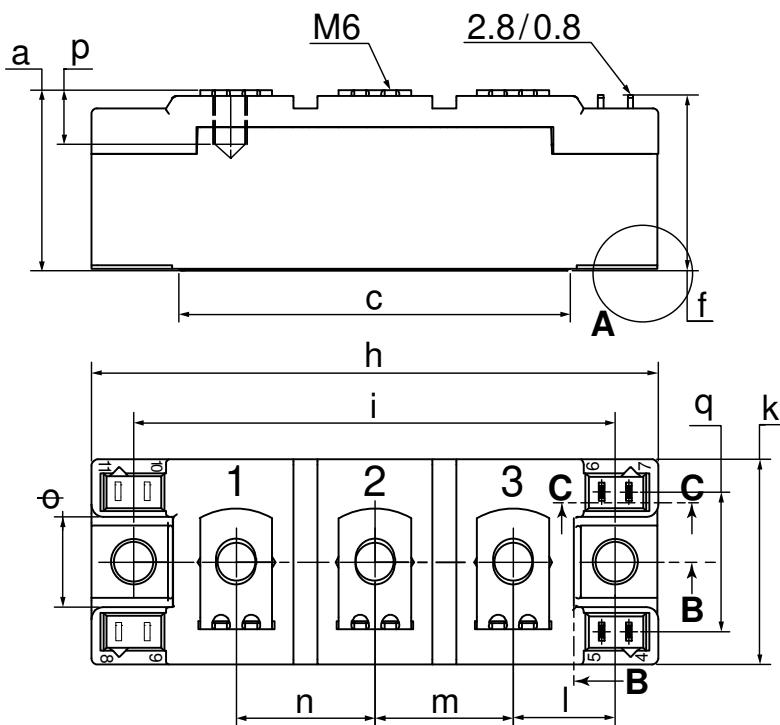
Data Matrix: part no. (1-19), DC + PI (20-25), lot.no.# (26-31), blank (32), serial no.#(33-36)

| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | MCC161-20io1    | MCC161-20io1       | Box           | 6        | 463507   |

**Equivalent Circuits for Simulation**

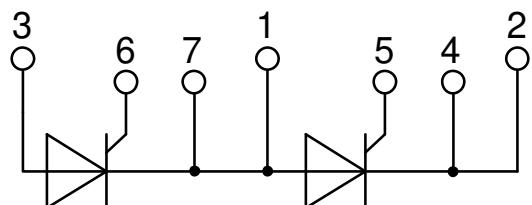
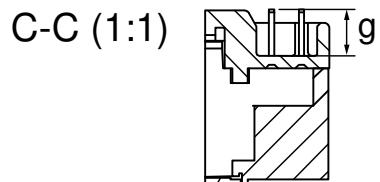
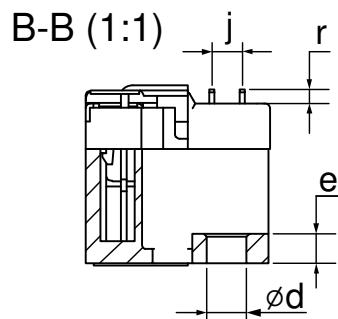
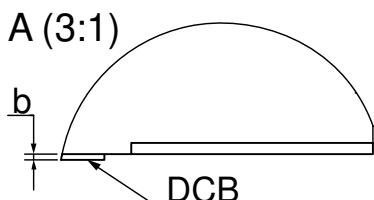
\* on die level

 $T_{VJ} = 125^\circ\text{C}$ 


**Outlines Y4**


| Dim. | MIN [mm]  | MAX [mm] | MIN [inch] | MAX [inch] |
|------|-----------|----------|------------|------------|
| a    | 30.0      | 30.6     | 1.181      | 1.205      |
| b    | typ. 0.25 |          | typ. 0.010 |            |
| c    | 64.0      | 65.0     | 2.520      | 2.559      |
| d    | 6.5       | 7.0      | 0.256      | 0.275      |
| e    | 4.9       | 5.1      | 0.193      | 0.201      |
| f    | 28.6      | 29.2     | 1.126      | 1.150      |
| g    | 7.3       | 7.7      | 0.287      | 0.303      |
| h    | 93.5      | 94.5     | 3.681      | 3.720      |
| i    | 79.5      | 80.5     | 3.130      | 3.169      |
| j    | 4.8       | 5.2      | 0.189      | 0.205      |
| k    | 33.4      | 34.0     | 1.315      | 1.339      |
| l    | 16.7      | 17.3     | 0.657      | 0.681      |
| m    | 22.7      | 23.3     | 0.894      | 0.917      |
| n    | 22.7      | 23.3     | 0.894      | 0.917      |
| o    | 14.0      | 15.0     | 0.551      | 0.591      |
| p    | typ. 10.5 |          | typ. 0.413 |            |
| q    | 22.8      | 23.3     | 0.898      | 0.917      |
| r    | 1.8       | 2.4      | 0.071      | 0.041      |

Optional accessories for modules  
Keyed gate/cathode twin plugs with wire length = 350 mm, gate = white, cathode = red  
Type ZY 180L (L = Left for pin pair 4/5)  
Type ZY 180R (R = Right for pin pair 6/7) } UL 758, style 3751



## Thyristor

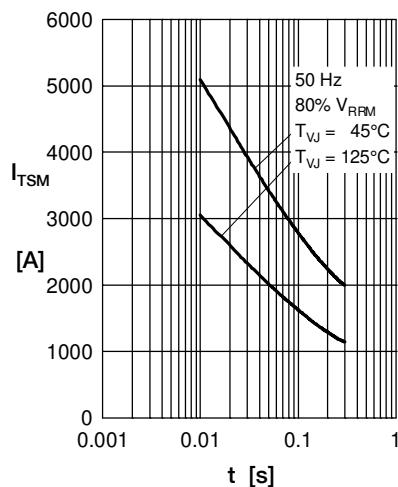


Fig. 1 Surge overload current  $I_{TSM}$ ,  
 $I_{FSM}$ : Crest value,  $t$ : duration

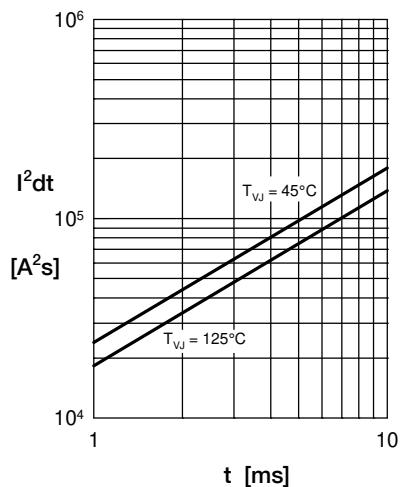


Fig. 2  $I^2t$  versus time (1-10 ms)

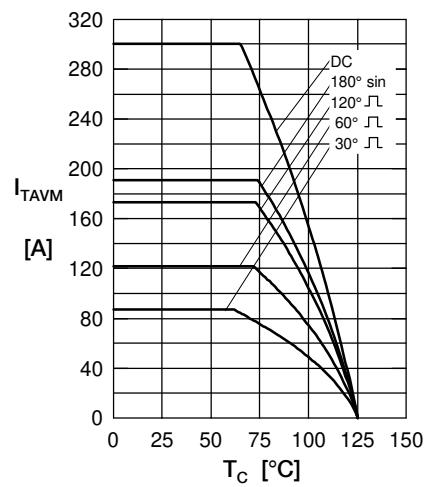


Fig. 3 Max. forward current  
at case temperature

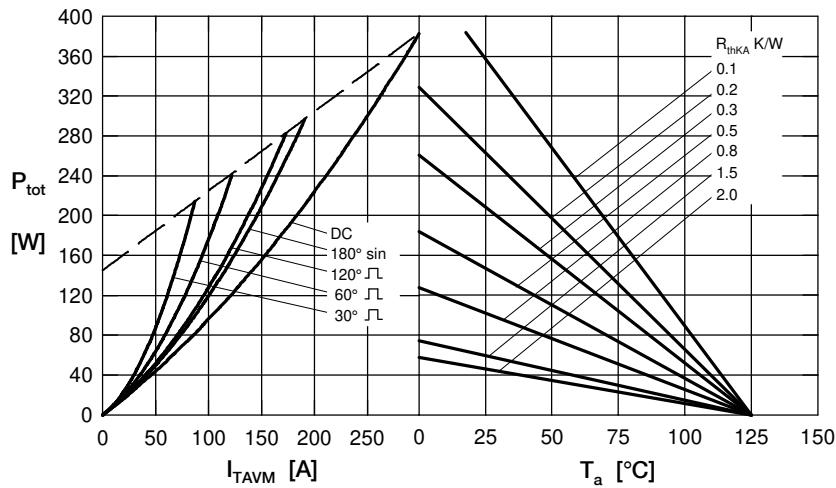


Fig. 4 Power dissipation vs. on-state current & ambient temperature  
(per thyristor or diode)

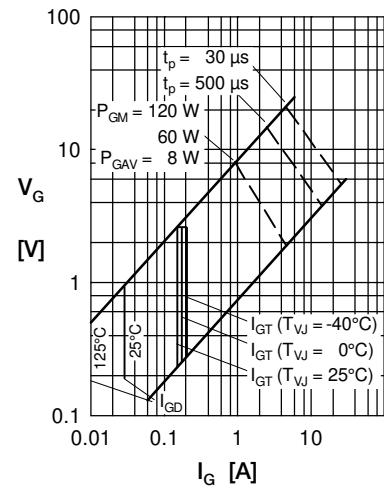


Fig. 5 Gate trigger characteristics

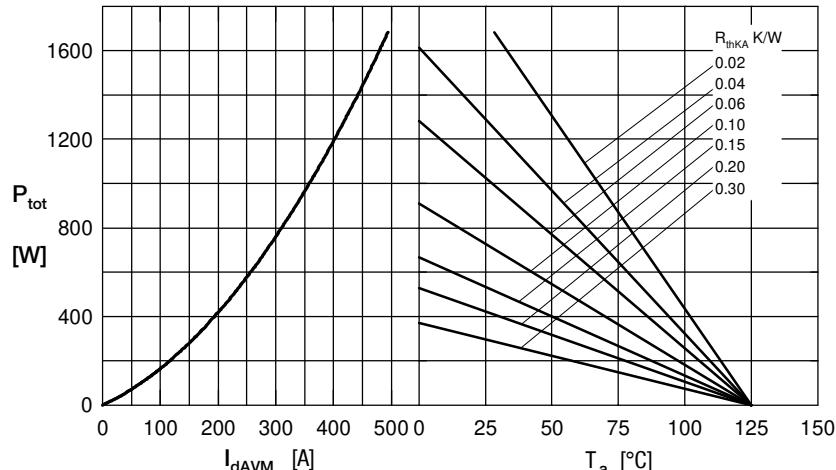


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

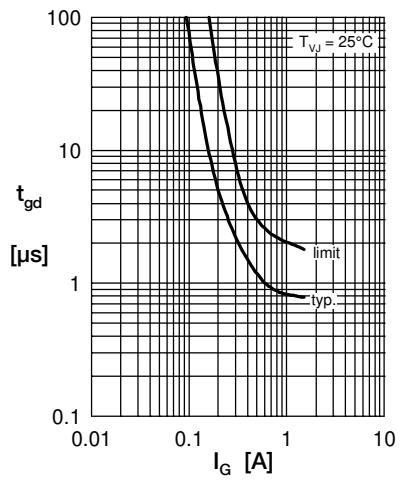


Fig. 7 Gate trigger delay time

## Thyristor

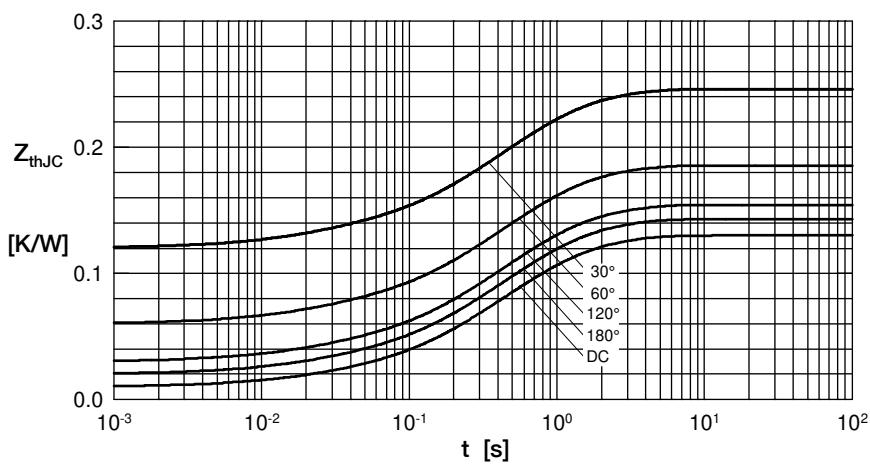


Fig. 8 Transient thermal impedance junction to case at various conduction angles

$R_{thJC}$  for various conduction angles  $d$ :

| $d$  | $R_{thJC}$ [ $K/W$ ] |
|------|----------------------|
| DC   | 0.155                |
| 180° | 0.171                |
| 120° | 0.184                |
| 60°  | 0.222                |
| 30°  | 0.294                |

Constants for  $Z_{thJC}$  calculation:

| $i$ | $R_{thi}$ [ $K/W$ ] | $t_i$ [s] |
|-----|---------------------|-----------|
| 1   | 0.012               | 0.00014   |
| 2   | 0.008               | 0.019     |
| 3   | 0.030               | 0.180     |
| 4   | 0.073               | 0.520     |
| 5   | 0.032               | 1.600     |